



# TIP41C

## NPN PLANAR TRANSISTOR

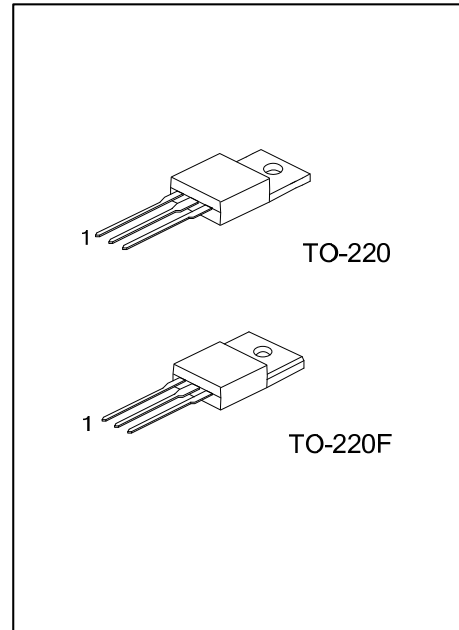
### NPN EXPITAXIAL PLANAR TRANSISTOR

■ DESCRIPTION

The UTC TIP41C is a NPN epitaxial planar transistor, designed for using in general purpose amplifier and switching applications.

■ FEATURE

\* Complement to TIP42C



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
TIP41CL-TA3-T	TIP41CG-TA3-T	TO-220	B	C	E	Tube
TIP41CL-TF3-T	TIP41CG-TF3-T	TO-220F	B	C	E	Tube

<p>TIP41CL-TA3-T</p> <p>(1)Packing Type</p> <p>(2)Package Type</p> <p>(3)Lead Free</p>	<p>(1) T: Tube</p> <p>(2) TA3: TO-220, TF3: TO-220F</p> <p>(3) G: Halogen Free, L: Lead Free</p>
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## NPN PLANAR TRANSISTOR

### ■ ABSOLUTE MAXIMUM RATINGS ( $T_C=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATING	UNIT
Collector Base Voltage		$V_{CBO}$	100	V
Collector to Emitter Voltage		$V_{CEO}$	100	V
Emitter-Base Voltage		$V_{EBO}$	5	V
Collector Current	DC	$I_C$	6	A
	Pulse		10	A
Base Current		$I_B$	2	A
Collector Dissipation	$T_C=25^\circ\text{C}$	TO-220	65	W
		TO-220F	22	
	$T_A=25^\circ\text{C}$	TO-220	2	W
		TO-220F	0.7	
Junction Temperature		$T_J$	150	$^\circ\text{C}$
Storage Temperature		$T_{STG}$	-65 ~ +150	$^\circ\text{C}$

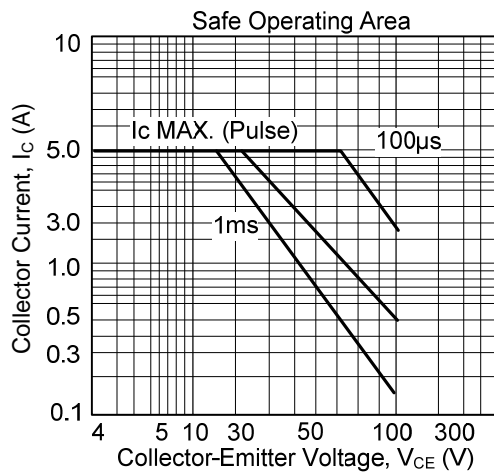
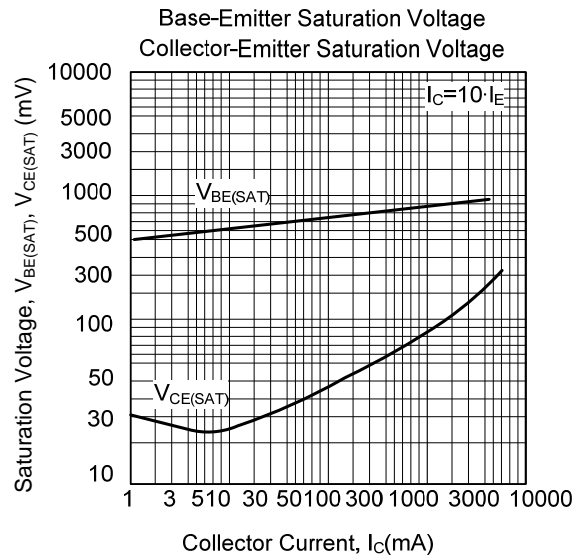
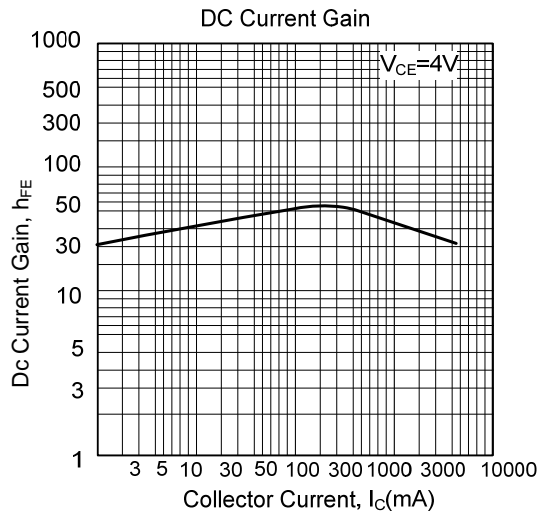
Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### ■ ELECTRICAL CHARACTERISTICS ( $T_C=25^\circ\text{C}$ )

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector Emitter Sustaining Voltage (Note)	$V_{CEO}$	$I_C=30\text{mA}$ , $I_B=0$	100			V
Collector Cutoff Current	$I_{CEO}$	$V_{CE}=60\text{V}$ , $I_B=0$			0.7	mA
Collector Cutoff Current	$I_{CES}$	$V_{CE}=100\text{V}$ , $V_{EB}=0$			400	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=5\text{V}$ , $I_C=0$			1	mA
Collector-Emitter Saturation Voltage (Note)	$V_{CE(SAT)}$	$I_C=6\text{A}$ , $I_B=600\text{mA}$			1.5	V
Base-Emitter On Voltage (Note)	$V_{BE(ON)}$	$I_C=6\text{A}$ , $V_{CE}=4\text{V}$			2.0	V
DC Current Gain (Note)	$h_{FE1}$	$I_C=300\text{mA}$ , $V_{CE}=4\text{V}$	30			
	$h_{FE2}$	$I_C=3\text{A}$ , $V_{CE}=4\text{V}$	15		75	
Current Gain Bandwidth Product	$f_T$	$V_{CE}=10\text{V}$ , $I_C=500\text{mA}$ , $f=1\text{MHz}$	3			MHz

Note: Pulse Test:  $P_W \leq 300\mu\text{s}$ , Duty Cycle  $\leq 2\%$

### TYPICAL CHARACTERISTICS



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